

An IATF 16949, ISO9001 and ISO 14001 Certified Company





#### PLASTIC POWER TRANSISTORS

BD241, A, B, C NPN BD242, A, B, C PNP





TO-220

#### **APPLICATIONS**

- 1. Intended for a wide variety of Switching and Amplifier Applications
- 2. Series and Shunt Regulators
- 3. Driver and Output stages of Hi-Fi Amplifiers

#### ABSOLUTE MAXIMUM RATINGS ( $T_a = 25$ °C)

DESCRIPTION	SYMBOL	BD241	BD241A	BD241B	BD241C	UNIT
DESCRIPTION		BD242	BD242A	BD242B	BD242C	UNII
Collector Emitter Voltage	$V_{CEO}$	45	60	80	100	V
Collector Base Voltage	$V_{CBO}$	55	70	90	115	V
Collector Emitter Voltage (RBE=100fi)	$V_{CER}$	55	70	90	115	٧
Emitter Base Voltage	$V_{EBO}$	5				٧
Collector Current Continuous	I <sub>C</sub>	5			Α	
Collector Current Peak	I <sub>CM</sub>	8			Α	
Base Current	I <sub>B</sub>	1			Α	
Power Dissipation upto Tc=25°C	$P_{D}$	40		W		
Power Dissipation upto Ta=25°C	В	2				W
Derate above 25°C	P <sub>D</sub>	16				mW/ºC
Storage Temperature	Tstg	- 65 to +150			°C	
Junction Temperature	$T_j$	150			°C	
THERMAL CHARACTERISTICS						
Junction to Case	Rth (j-c) 3.12			°C/W		
Junction to Ambient in free air	Rth (j-a)	62.5			°C/W	







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#### **ELECTRICAL CHARACTERISTICS**

PARAME	TER	SYMBOL	TEST CONDITIONS	MIN	MAX	UNIT
Collector Emitter (sus) Voltage	BD241/242	*\/	I <sub>C</sub> =30mA, I <sub>B</sub> =0	45	-	V
	BD241A/242A			60	-	V
	BD241B/242B	V <sub>CEO(sus)</sub>		80	-	V
	BD241C/242C			100	-	V
Collector Cut Off	BD241A/242A	ı	$V_{CE}$ =30V, $I_{B}$ =0	-	0.3	mA
Current	BD241B,C/242B,C	I <sub>CEO</sub>	$V_{CE}$ =60V, $I_{B}$ =0	-	0.3	mA
Collector Cut Off Curren	t	I <sub>CES</sub>	V <sub>CE</sub> =V <sub>CEO</sub> (max),	-	0.2	mA
Emitter Cut Off Current		I <sub>EBO</sub>	$V_{EB}$ =5V, $I_{C}$ =0	-	1	mA
DC Current Gain		* -	$I_C$ =1A, $V_{CE}$ =4V	25	-	1
DC Current Gain		*h <sub>FE</sub>	$I_C$ =3A, $V_{CE}$ =4V	10	-	1
Collector Emitter Saturation Voltage		*V <sub>CE (sat)</sub>	$I_{C}$ =3A, $I_{B}$ =0.6A	-	1.2	V
Base Emitter On Voltage			$I_C=3A$ , $V_{CE}=4V$	-	1.8	V
*Pulse Test : Pulse wid	th <300ms, Duty Cy		•			
DYNAMIC CHARACTER	RISTIC					
Small Signal Current Gain		h <sub>fe</sub>	I <sub>C</sub> =0.5A, V <sub>CE</sub> =10V,	20	-	1
Transition Frequency		f <sub>T</sub>	IC=0.5A, VCE=10V,	3	-	MHz
Turn Off Breakdown Energy		E <sub>(BR)</sub>	L=20mH, lcc=1.22A PNP	15	-	mJ
			L=20mH, Icc=1.8A NPN	32	-	mJ
SWITCHING CHARACT	ERISTICS			_		
Turn On Time		<b>t</b> on	Vcc=20V, Ic=1A,	0.3		μS
Turn Off Time		<b>t</b> off	I <sub>B1</sub> =I <sub>B2</sub> =0.1A	1		μS

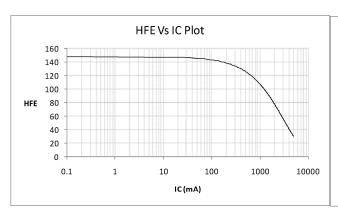


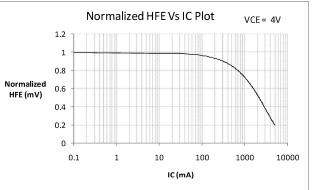
**TYPICAL CHARACTERISTICS CURVES** 

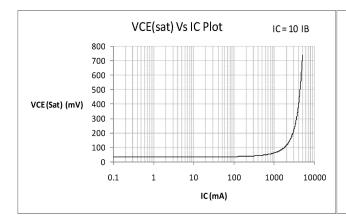


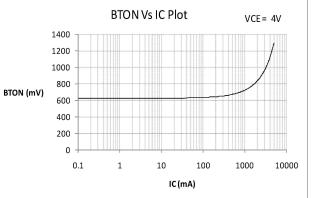


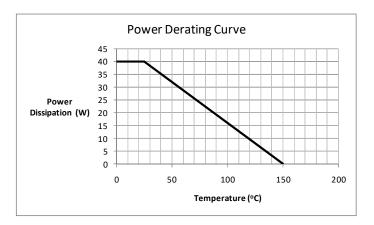
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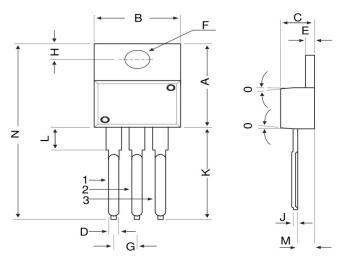






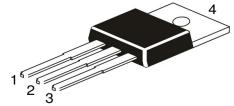


#### **PACKGE DETAILS**



DIM	MIN	MAX	
Α	14.42	16.51	
В	9.63	10.67	
С	3.56	4.83	
D		0.90	
E	1.15	1.40	
F	3.75	3.88	
G	2.29	2.79	
Н	2.54	3.43	
J	_	0.56	
K	12.70	14.73	
L	2.80	4.07	
М	2.03	2.92	
N	_	31.24	
0	7 DEG		

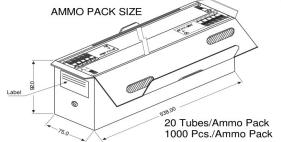
All diminsions in mm.



#### Pin Configuration

- 1. Base
- 2. Collector
- 3. Emitter
- 4. Collector

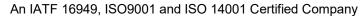
# TO-220 Tube Packing End Pin 13.74 DEVICE NAME Sr. OTY. 50 Pcs./Tube AMMO PACK SIZE



#### **Packing Detail**

PACKAGE	STANDA	ARD PACK	INNER CARTON BOX		OUTER CARTON BOX		
	Details	Net Weight/Qty	Size	Qty	Size	Qty	GrWt
TO-220 /FP	200 pcs/polybag 50 pcs/tube	396 gm/200 pcs 120 gm/50 pcs	3'x7.5'x7.5' 3.5'x3.7'x21.5'	1.0K 1.0K	17''x 15''x 13.5'' 19''x 19''x 19'	16.0K 10.0K	36 kgs 29 kgs









# Recommended Product Storage Environment for Discrete Semiconductor Devices

This storage environment assumes that the Diodes and transistors are packed properly inside the original packing supplied by CDIL.

- · Temperature 5 °C to 30 °C
- Humidity between 40 to 70 %RH
- · Air should be clean.
- · Avoid harmful gas or dust.
- · Avoid outdoor exposure or storage in areas subject to rain or water spraying .
- · Avoid storage in areas subject to corrosive gas or dust. Product shall not be stored in areas exposed to direct sunlight.
- · Avoid rapid change of temperature.
- · Avoid condensation.
- · Mechanical stress such as vibration and impact shall be avoided.
- · The product shall not be placed directly on the floor.
- The product shall be stored on a plane area. They should not be turned upside down. They should not be placed against the wall.

#### **Shelf Life of CDIL Products**

The shelf life of products is the period from product manufacture to shipment to customers. The product can be unconditionally shipped within this period. The period is defined as 2 years.

If products are stored longer than the shelf life of 2 years the products shall be subjected to quality check as per CDIL quality procedure.

The products are further warranted for another one year after the date of shipment subject to the above conditions in CDIL original packing.

#### Floor Life of CDIL Products and MSL Level

When the products are opened from the original packing, the floor life will start.

For this, the following JEDEC table may be referred:

JEDEC MSL Level				
Level	Time	Condition		
1	Unlimited	≤30 °C / 85% RH		
2	1 Year	≤30 °C / 60% RH		
2a	4 Weeks	≤30 °C / 60% RH		
3	168 Hours	≤30 °C / 60% RH		
4	72 Hours	≤30 °C / 60% RH		
5	48 Hours	≤30 °C / 60% RH		
5a	24 Hours	≤30 °C / 60% RH		
6	Time on Label(TOL)	≤30 °C / 60% RH		

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#### **Customer Notes**

#### **Component Disposal Instructions**

- CDIL Semiconductor Devices are RoHS compliant, customers are requested to please dispose as per prevailing Environmental Legislation of their Country.
- 2. In Europe, please dispose as per EU Directive 2002/96/EC on Waste Electrical and Electronic Equipment (WEEE).

#### **Disclaimer**

The product information and the selection guides facilitate selection of the CDIL's Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished in the Data Sheet and on the CDIL Web Site/CD are believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

CDIL strives for continuous improvement and reserves the right to change the specifications of its products without prior notice.



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